

Green Products

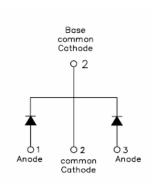
MBR20135/150CT SCHOTTKY RECTIFIER

Applications:

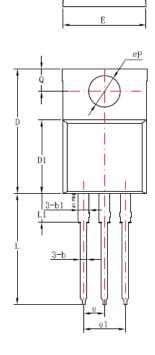
- · Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection

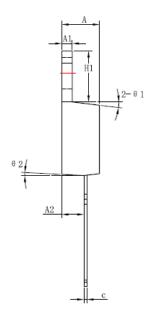
Features:

- 175 °C T_J operation
- Center tap configuration
- Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- High frequency operation
- · Guard ring for enhanced ruggedness and long term reliability
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request



Mechanical Dimensions: In mm





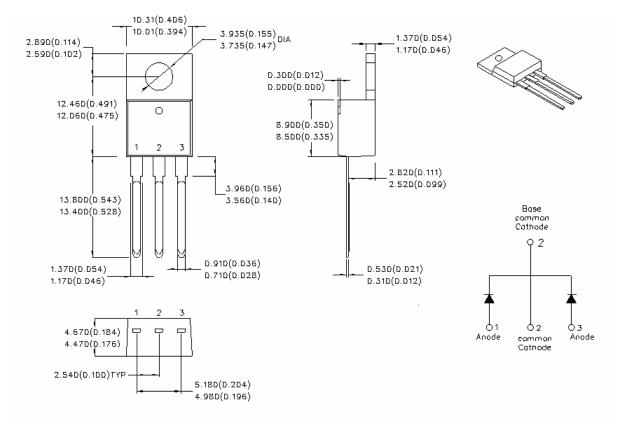
	Dimensions in			
Symbol		millimeters Typical Max 4.57 4.72 1.27 1.37 2.69 2.89 0.81 0.96 1.27 0.38 0.61 1.5.24 15.54 9.00 9.15 1.0.16 10.31 2.54 5.06 6.24 6.44	3	
_	Min	Typical	Max	
Α	4.42	4.57	4.72	
A1	1.17	1.27	1.37	
A2	2.59	2.69	2.89	
b	0.71	0.81	0.96	
b1		1.27		
С	0.36	0.38	0.61	
D	14.94	15.24	15.54	
D1	8.85	9.00	9.15	
E	10.01	10.16	10.31	
е		2.54		
e1		5.06		
H1	6.04	6.24	6.44	
L	12.7	13.56	13.78	
L1		3.5		
ФР	3.74	3.84	4.04	
Q	2.54	2.74	2.94	
Θ1		7°		
Θ2		3°		
Θ3		4°		

OPTION1(HD)

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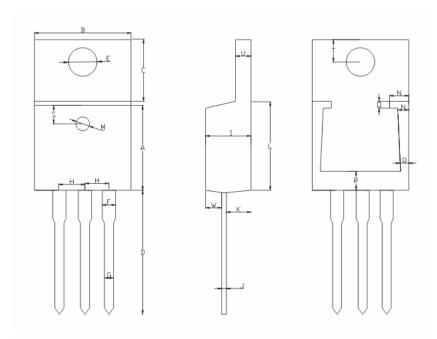


OPTION 2(CJ)

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A: 8. 5±0.5	B: 9. 5±0. 5	C:6.4±0.5	D:14.1±1
E: 3. 84 ± 0. 03	F: 1.27±0.03	G:0.85±0.10	H:2.54±0.025
I:4.6±0.5	J:0.38±0.015	K:2.75±025	L:9.0±0.5
M: 1.5±0.05	N: 1.8±0.05	0:0.5±0.05	P:1.2±0.05
Q: 0. 9±0. 05	R: 3. 2±0. 05	S:1.55±0.05	T:2.8±0.15
U: 1. 27 ± 0. 05	W: 1.27±0.03		

OPTION 3(SR)

TO-220AB



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Marking Diagram:



Where XXXXX is YYWWL

MBR = Device Type

20 = Forward Current (20A) 135 = Reverse Voltage (135V)

CT = Configuration

SSG = SSG YY = Year WW = Week L = Lot Number

Cautions: Molding resin Epoxy resin UL:94V-0

Ordering Information:

Device	Package	Shipping
MBR20135CT	TO-220AB	FOnce / tube
MBR20150CT	(Pb-Free)	50pcs / tube

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification.

Maximum Ratings:

Characteristics	Symbol	Condition		Max.	Units
Peak Inverse Voltage	V	_	135	MBR20135CT	V
Feak inverse voltage	V_{RWM}	-	150	MBR20150CT	V
Maximum RMS Voltage	V_{RMS}	-	105		V
Max. Average Forward	1	50% duty cycle @T _C =125℃,	10(Per leg)		A
	I _{F(AV)}	rectangular wave form	20(Per device)		
Peak Repetitive Surge current (Rated V _R ,	I _{RRM}	-		1.0	А
Square Wave,20KHz)	-TCICWI				
Max. Peak One Cycle					
Non-Repetitive Surge	I _{FSM}	8.3 ms, half Sine pulse		150	Α
Current	'FSIVI	o.o mo, nan omo paleo		100	, ,
(per leg)					

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Electrical Characteristics:

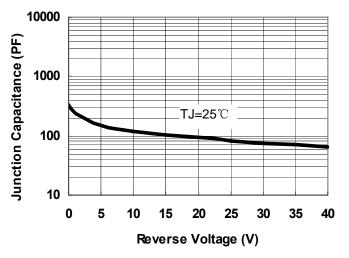
Characteristics	Symbol	Condition		Max.	Units
Max. Forward Voltage Drop	V_{F1}	@ 10A, Pulse, T _J = 25 ℃	_	0.90	V
(per leg)*	V _{F2}	@ 10A, Pulse, T _J = 125 ℃		0.83	V
Max. Reverse Current	I _{R1}	@V _R = rated VR	Max.	0.50	mA
(per leg)*		T _J = 25 ℃	Typical	0.01	
	I _{R2}	@V _R = rated VR		5.0	mA
		T _J = 125 ℃			
Max. Junction Capacitance	C_T	@V _R = 5V, T _C = 25 ℃		400	pF
(per leg)		f _{SIG} = 1MHz			
Typical Series Inductance	L _S	Measured lead to lead 5 mm from package		8.0	nΗ
(per leg)		body			
Max. Voltage Rate of	dv/dt	-		10,000	V/s
Change					

^{*} Pulse Width < 300µs, Duty Cycle <2%

Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specification	Units
Max. Junction Temperature	T_J	-	-55 to +175	${\mathbb C}$
Max. Storage Temperature	T _{stg}	-	-55 to +150	$^{\circ}$
Maximum Thermal Resistance Junction to Case (per leg)	R _{θJC}	DC operation	1.5	°C/W
Maximum Thermal Resistance, Case to Heat Sink	$R_{\theta CS}$	Mounting surface, smooth and greased(only for TO-220)	0.50	°C/W

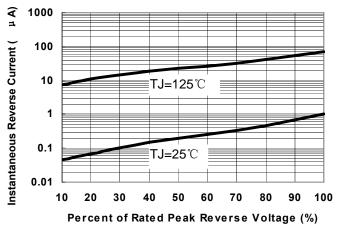
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25 Average Forward Current (A) 20 15 10 5 RESISTIVE OR INDUCTIVELOAD 0 25 50 75 100 125 0 150 175 Case Temperature°C

Fig.1-Typical Junction Capacitance

Fig.2-Forward current derating curve



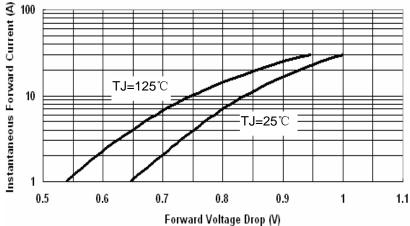


Fig.3-Typical Reverse Characteristics

Fig.4-Typical Instantaneous Forward Voltage Characteristics

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MBR20135CT/150CT

Technical Data Data Sheet N0625, Rev. - **Green Products**

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